

Supporting Information

Theory-Guided Synthesis of Highly Luminescent Colloidal Cesium Tin Halide Perovskite Nanocrystals

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Detailed method for the calculation of the average lifetime, radiative and non-radiative recombination rates: We used the following method to roughly evaluate the radiative and nonradiative recombination rates. The photoluminescence quantum yield (PLQY) is defined as the ratio of emitted photons per absorbed photons. The radiative recombination and the non-radiative recombination both depopulated the excited state. Hence, the PLQY is also defined as the ratio of the radiative recombination rate to the total recombination rate, given by equation (1),

$$PLQY = \frac{\Gamma_{rad}}{\Gamma_{rad} + \Gamma_{non-rad}} \quad (1)$$

where Γ_{rad} and $\Gamma_{non-rad}$ are the radiative and non-radiative recombination rates, respectively.

The lifetime of the excited state refers to the average residence time of the photon in the excited state before returning to the ground state. The average lifetime is the reciprocal of the total recombination rate, which is calculated using the following equation,

$$\tau_{ave} = \frac{1}{\Gamma_{rad} + \Gamma_{non-rad}} \quad (2)$$

where τ_{ave} is the average lifetime. The decays of CsSnI₃ NCs were fitted by a single-, bi- or tri-exponential function,

$$I(t) = A_1 e^{-t/\tau_1} + A_2 e^{-t/\tau_2} + A_3 e^{-t/\tau_3} + \dots A_0 \quad (3)$$

where A_i ($i=1, 2$, and 3) and τ_i ($i=1, 2$, and 3) are the amplitudes and the corresponding fitted lifetimes, respectively, A_0 is a constant. The average lifetime (τ_{ave}) was calculated as follows,

$$\tau_{ave} = (A_1 \tau_1^2 + A_2 \tau_2^2 + A_3 \tau_3^2 + \dots) / (A_1 \tau_1 + A_2 \tau_2 + A_3 \tau_3 + \dots) \quad (4)$$

Based on the PLQY and τ_{ave} , we calculated the radiative and non-radiative recombination rates as follows,

$$\Gamma_{rad} = \frac{PLQY}{\tau_{ave}} \quad (5)$$

$$\Gamma_{non-rad} = \frac{1}{\tau_{ave}} - \Gamma_{rad} = \frac{1 - PLQY}{\tau_{ave}} \quad (6)$$

Defect calculations at the HSE06+SOC level. The HSE06 including SOC was also used to calculate defect formation energies and defect charge-transition levels. The contribution of the Hartree-Fock exchange potential was set at 0.25, and the plane-wave basis set cutoff of the wavefunctions was set at 400 eV. In equilibrium growth conditions, the chemical potential μ_i should satisfy the following equations: $\mu_{Cs} + \mu_{Sn} + 3\mu_I = \Delta H (CsSnI_3) = -7.35$ eV; $\mu_{Sn} + 2\mu_I < \Delta H (SnI_2) = -1.76$ eV; $\mu_{Cs} + \mu_I < \Delta H (CsI) = -5.31$ eV.

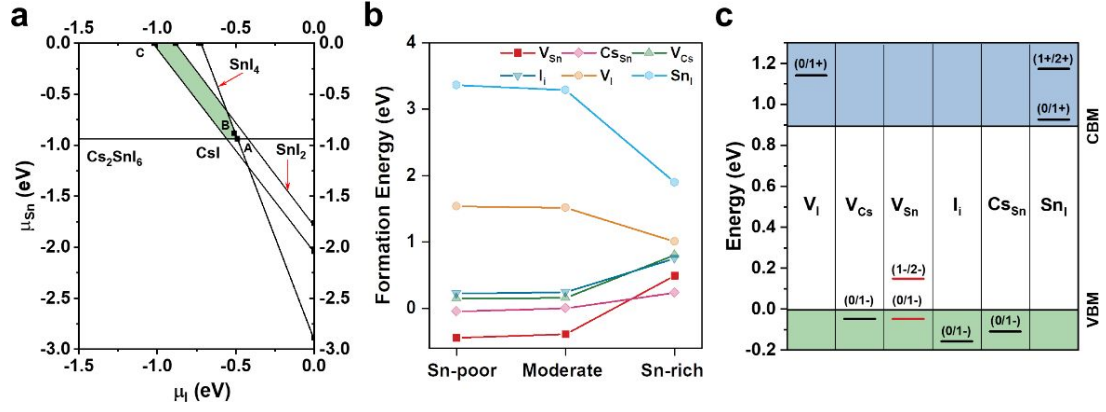


Figure S1. (a) Stability regions of different compounds vs. I and Sn chemical potentials of CsSnI₃. The shaded region indicates the equilibrium chemical potential region. The representative points (A: Sn-poor/I-rich, B: moderate, C: Sn-rich/I-poor conditions) are chosen for the defect formation energy calculations. (b) Calculated defect formation energies for 2×2×2 orthorhombic CsSnI₃ supercell at Sn-poor/I-rich, moderate, and Sn-rich/I-poor conditions, corresponding to A, B, C point in (a), respectively. (c) Defect charge-transition levels of CsSnI₃. These calculations were performed at the HSE06+SOC level of theory.

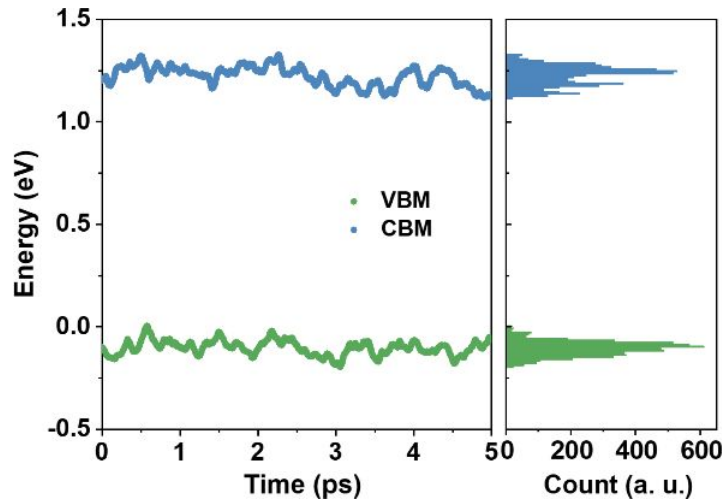


Figure S2. Time evolution of the VBM and CBM for 2×2×2 CsSnI₃ supercell with Cs_{Sn} at 300 K. The fluctuation widths of VBM and CBM for pristine CsSnI₃ are 0.200 and 0.209 eV, respectively.

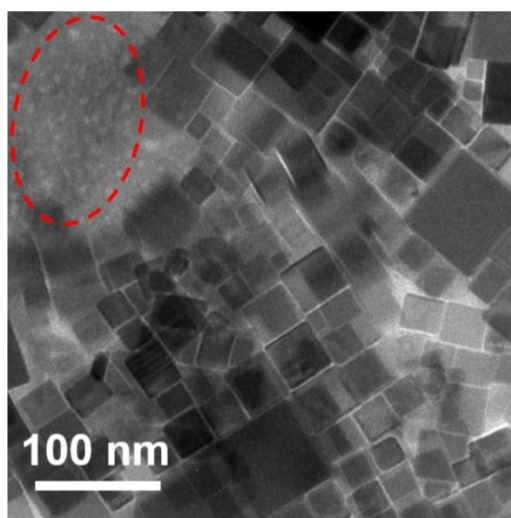


Figure S3. Low-magnification TEM image of 0.25:4.8. The area in the plotted ellipse indicates the presence of some byproducts.

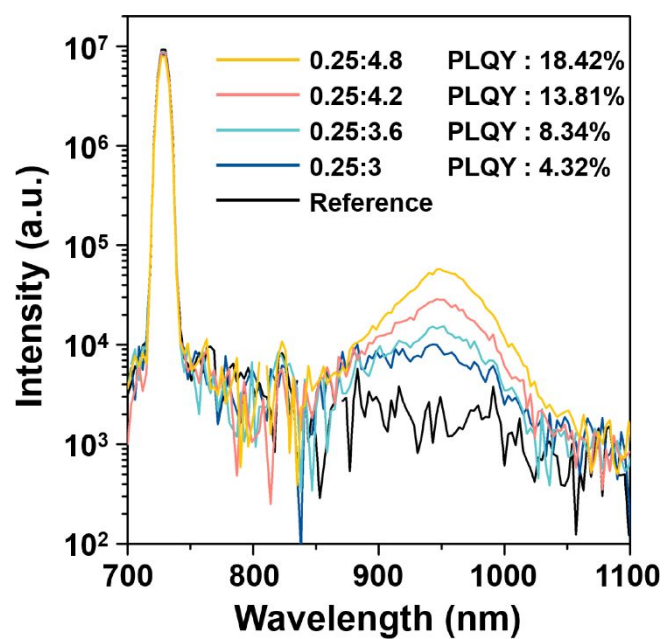


Figure S4. PLQY measurements of CsSnI_3 NCs prepared with different Cs:Sn precursor ratios.

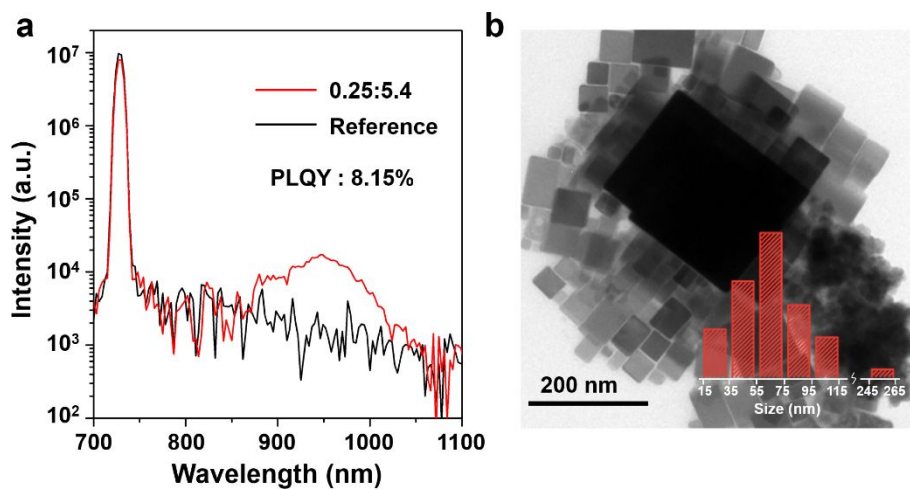


Figure S5. (a) PLQY measurement and (b) TEM image of 0.25:5.4. Inset in (b) shows the histogram of edge lengths of corresponding NCs.

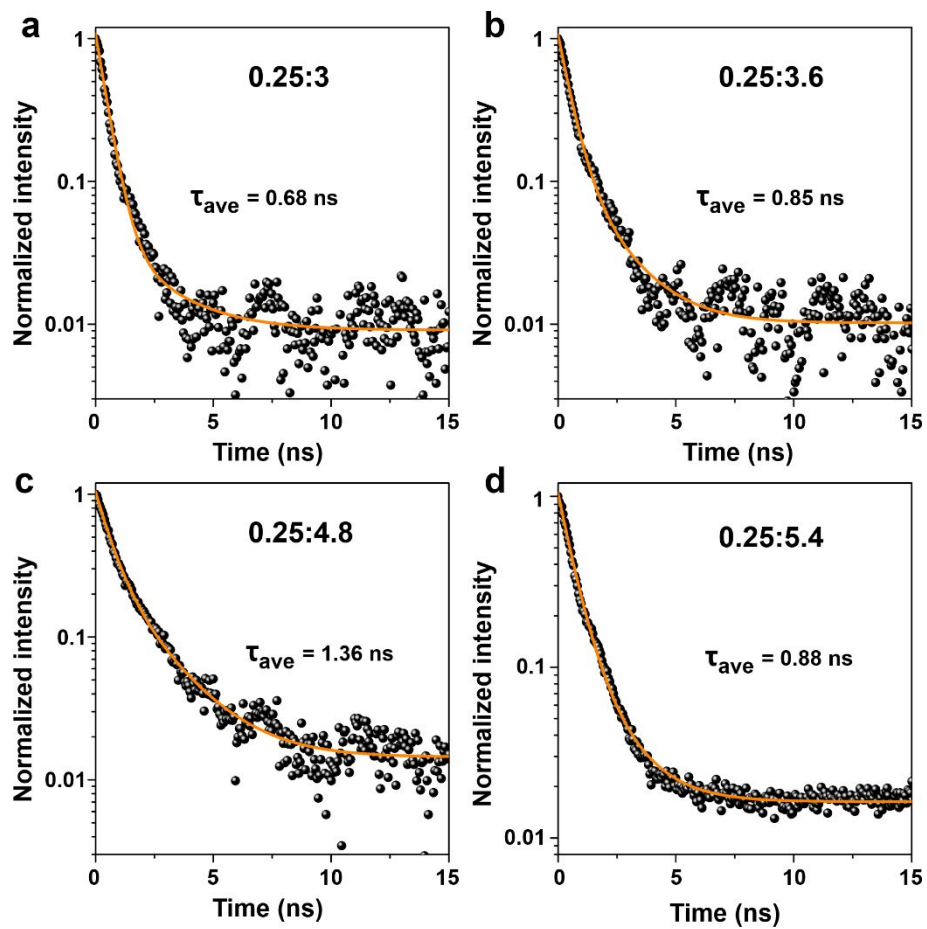


Figure S6. PL decays (black dots) and fitted curves (red lines) of (a) 0.25:3, (b) 0.25:3.6, (c) 0.25:4.8, and (d) 0.25:5.4 NCs.

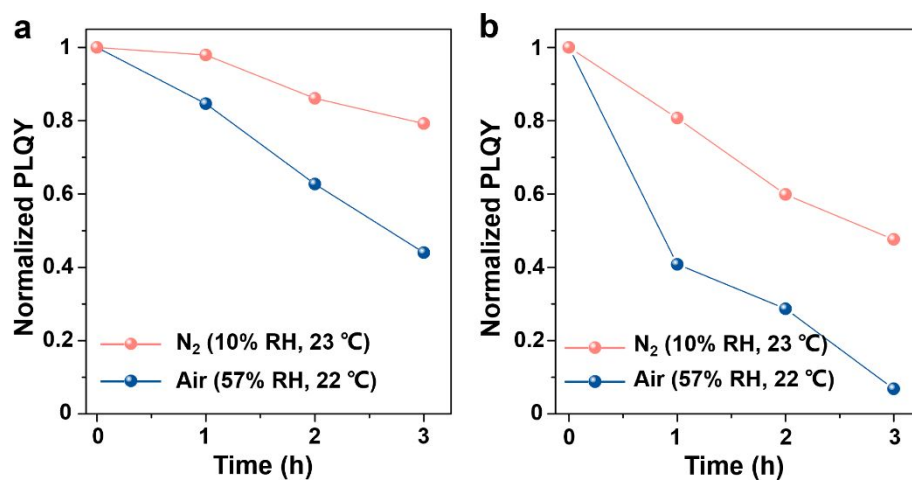


Figure S7. a) Temporal evolution of PLQYs of 0.25:4.2 NCs dispersed in hexane in air (57% relative humidity, RH) and under N₂ atmosphere (10% RH). For OAm and OA, their combination with NCs is highly dynamic and labile. This degradation can be linked to the low density of ligands on the surface. b) Temporal evolution of PLQYs of the CsSnI₃ NCs synthesized according to the reported strategy.¹

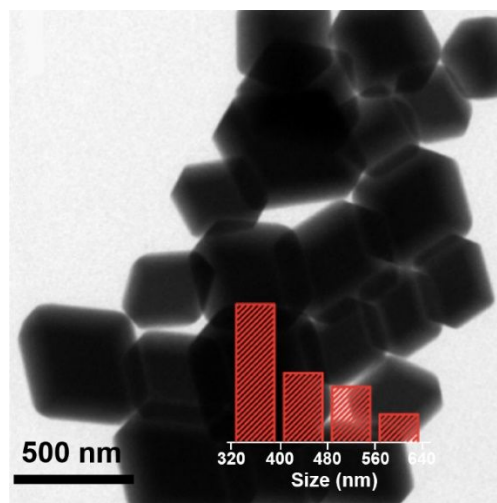


Figure S8. Low-magnification TEM image of 0.25:4.2:2 NCs. Inset shows the histogram of edge lengths of corresponding NCs.

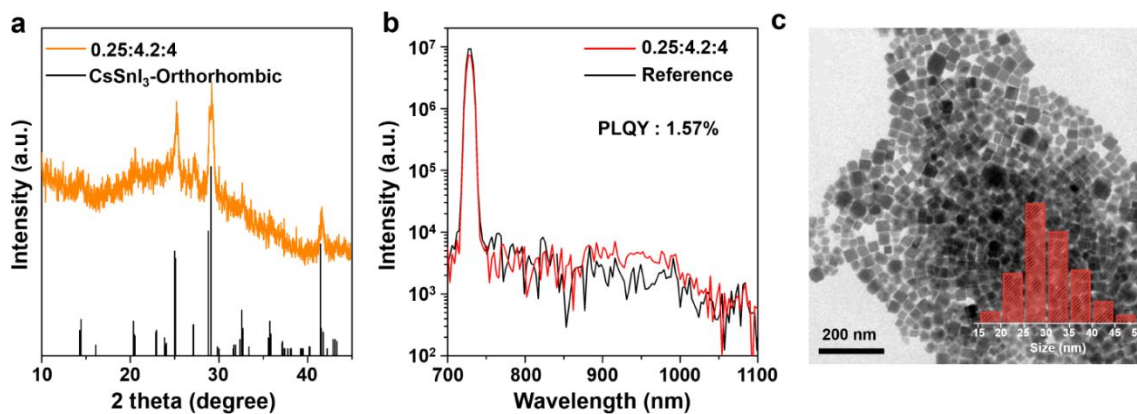


Figure S9. (a) XRD pattern of 0.25:4.2:4 NCs. (b) PLQY measurement and (c) TEM image of 0.25:4.2:4 NCs. Inset in (c) shows the histogram of edge lengths of corresponding NCs.

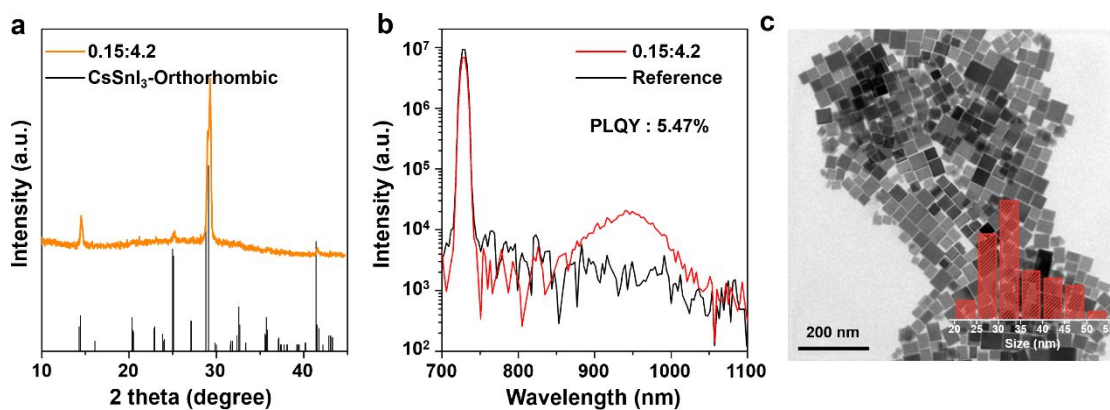


Figure S10. (a) XRD pattern of 0.15:4.2 NCs. (b) PLQY measurement and (c) TEM image of 0.15:4.2 NCs. Inset in (c) shows the histogram of edge lengths of corresponding NCs.

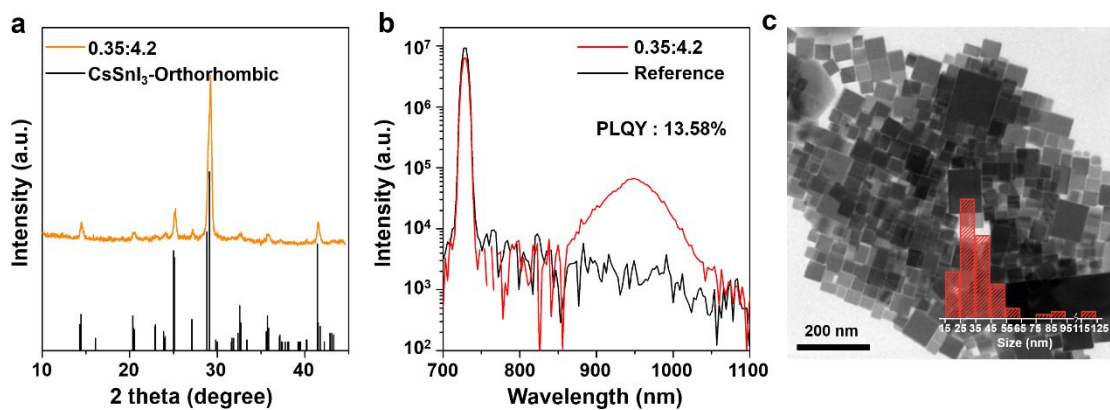


Figure S11. (a) XRD pattern of 0.35:4.2 NCs. (b) PLQY measurement and (c) TEM image of 0.35:4.2 NCs. Inset in (c) shows the histogram of edge lengths of corresponding NCs.

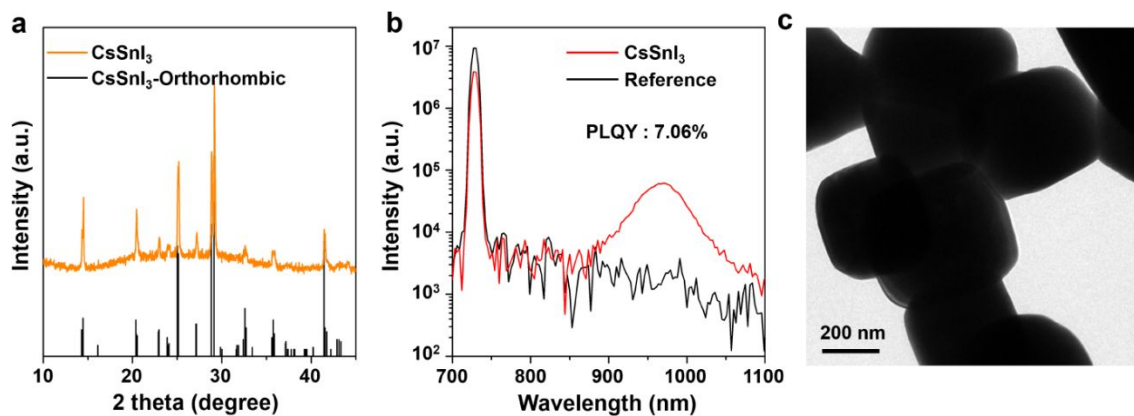


Figure S12. (a) XRD pattern, (b) PLQY measurement, and (c) TEM image of the product. CsSnI_3 was synthesized by replacing TMSI with equimolar amount of benzoyl iodine, while keeping the other synthetic parameters same with those of 0.25:4.2.

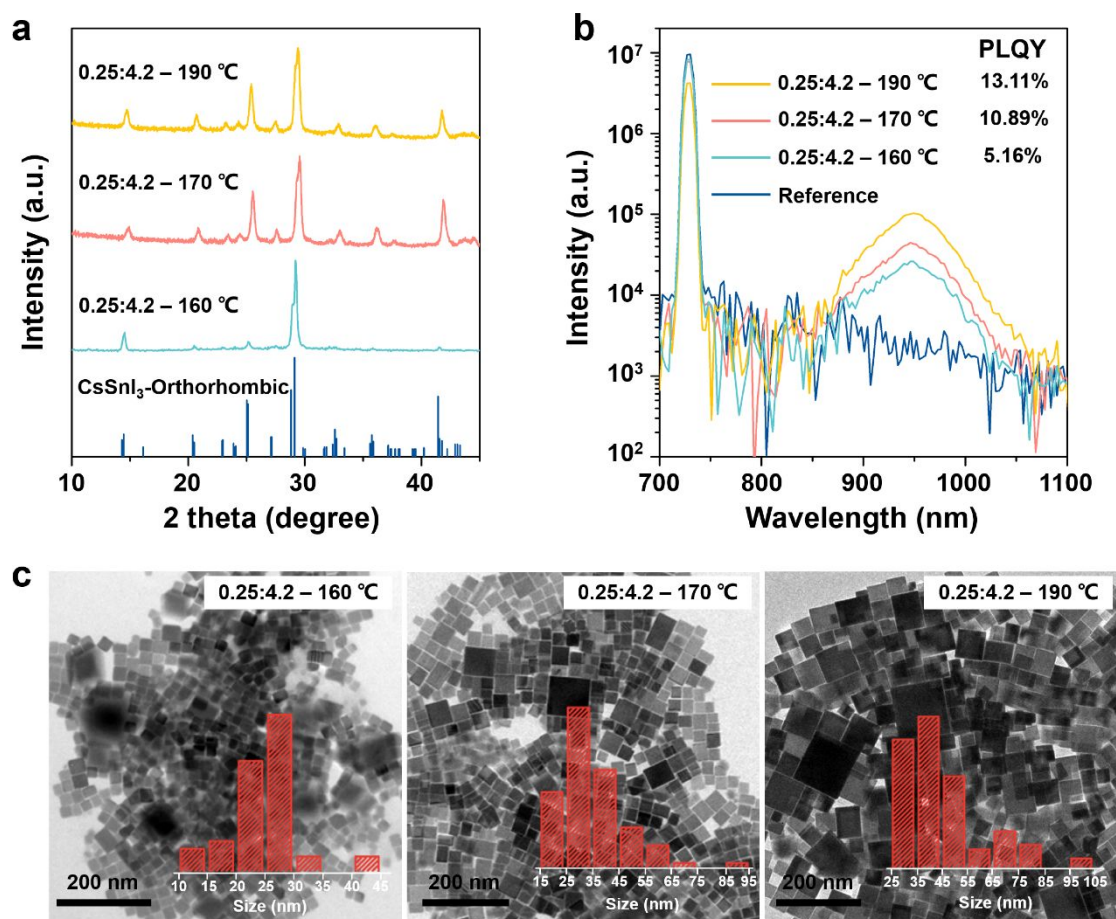


Figure S13. (a) XRD patterns, (b) PLQY measurement, and (c) TEM images of CsSnI₃ NCs synthesized at different temperatures. We note that the PLQYs and size of CsSnI₃ NCs increase with increasing reaction temperatures.

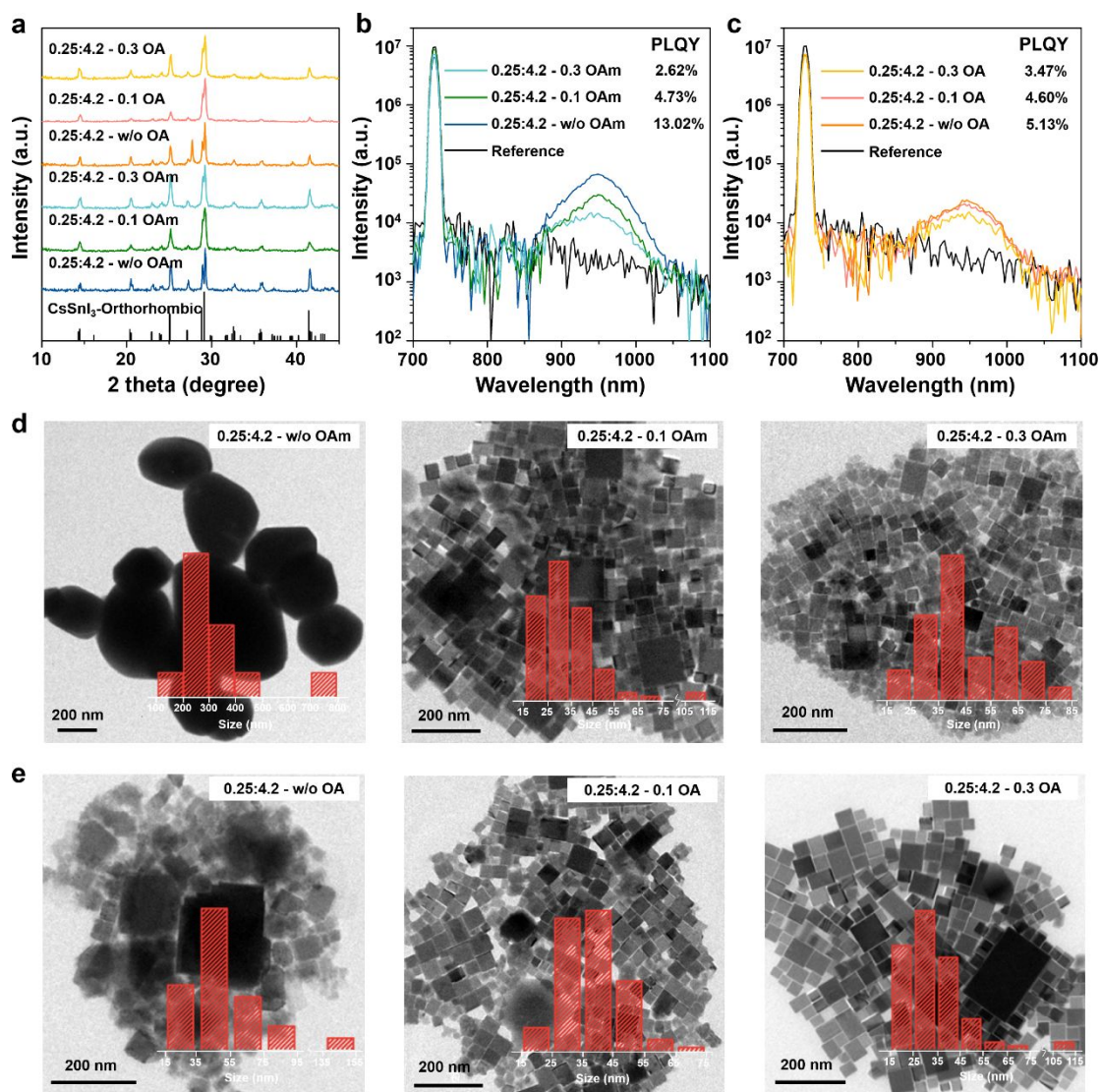


Figure S14. (a) XRD patterns, (b, c) PLQY measurement, and (d, e) TEM images of CsSnI₃ NCs synthesized with different amounts of OA and OAm. The detailed synthetic parameters are shown in Table S1. The final size of 0.25:4.2-w/o OAm exceeds 100 nm (Figure S14d, on the left), indicating that OAm plays a very important role in controlling the growth rate of CsSnI₃. The larger the size, the smaller the specific surface area. That is, less defects on the surface of NCs could contribute to the high PLQY.

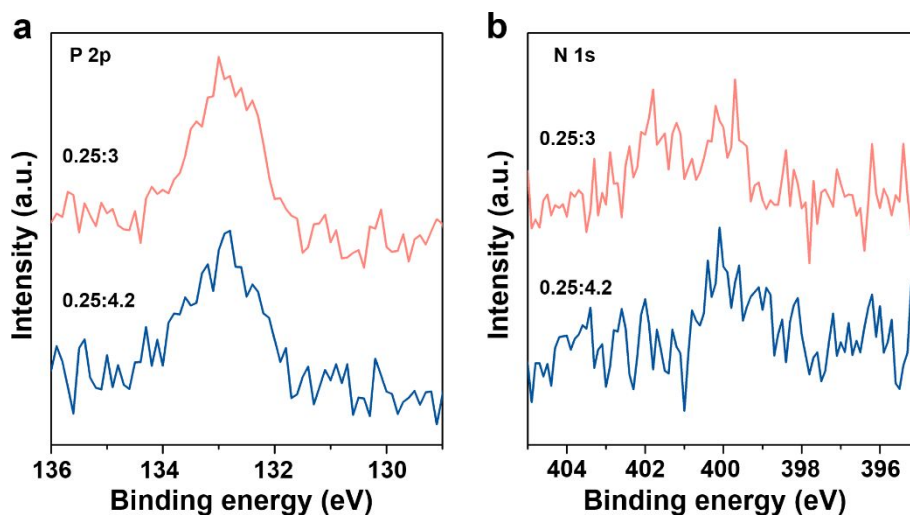


Figure S15. High-resolution XPS spectra of (a) P 2p and (b) N 1s for 0.25:3 and 0.25:4.2 NCs. The binding energies were calibrated using the free carbon C 1s peak at 284.8 eV.

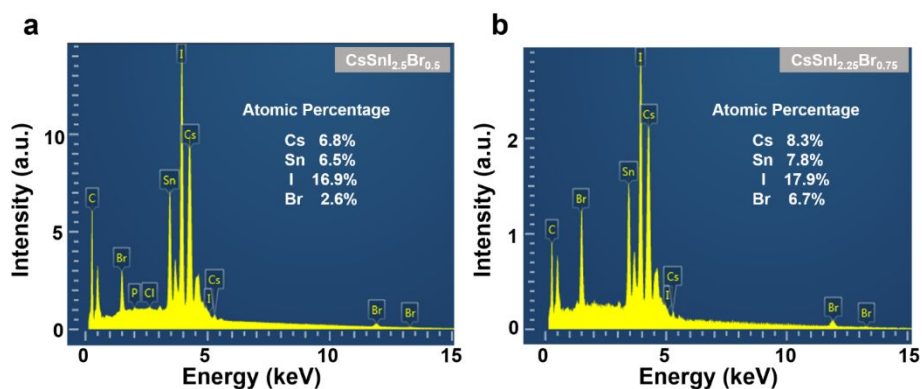


Figure S16. EDS of (a) CsSnI_{2.5}Br_{0.5} and (b) CsSnI_{2.25}Br_{0.75} NCs. Note that we used the nominal compositions for denoting the products.

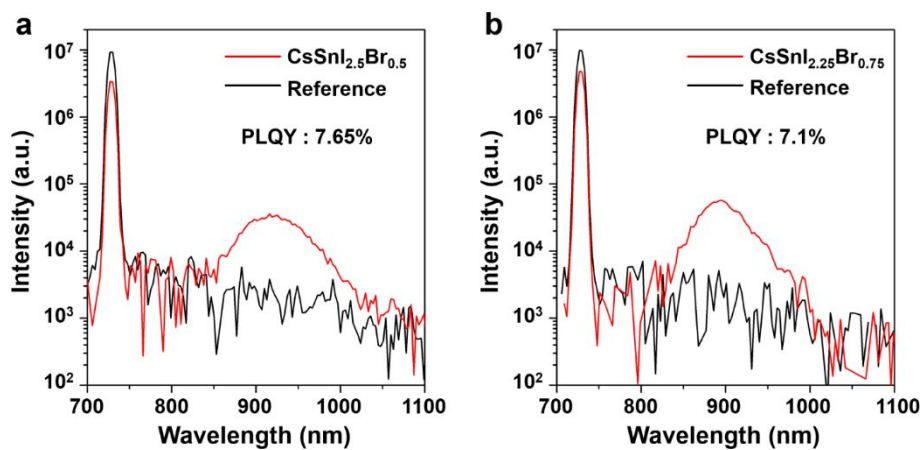


Figure S17. PLQY measurement of (a) $\text{CsSnI}_{2.5}\text{Br}_{0.5}$ and (b) $\text{CsSnI}_{2.25}\text{Br}_{0.75}$ NCs.

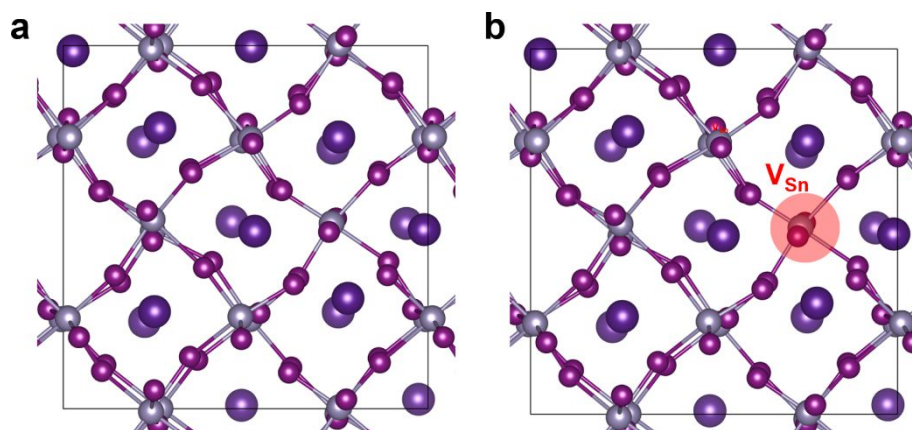


Figure S18. (a) 2×2×2 pristine CsSnI_3 and (b) CsSnI_3 supercell with V_{Sn} used for the MD simulations.

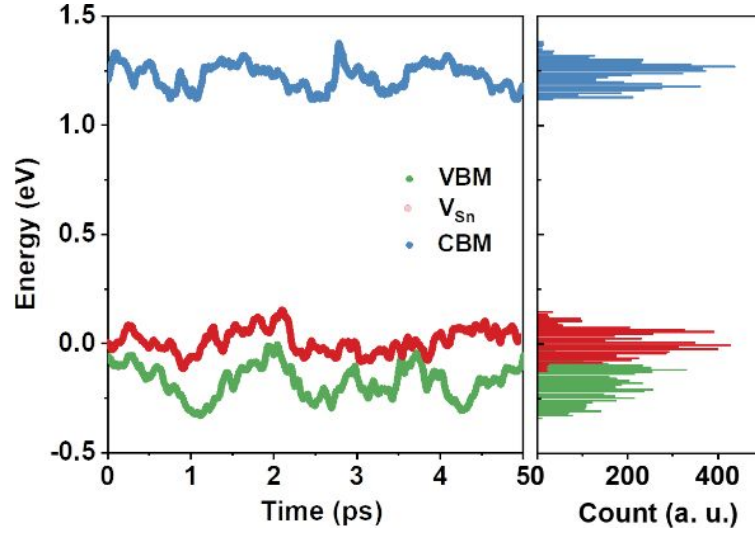


Figure S19. Time evolution of the VBM and CBM for $2 \times 2 \times 1$ CsSnI₃ supercell with V_{Sn} at 300 K. The fluctuation widths of VBM and CBM are 0.327 and 0.257 eV, respectively.

Table S1. Synthetic parameters used for the synthesis of CsSnI₃, CsSnI_{2.5}Br_{0.5}, and CsSnI_{2.25}Br_{0.75} NCs. We note that 0.25:4.2:2 and 0.25:4.2:4 NCs are denoted by the molar ratio of Cs, Sn and I precursors, while for the 0.25:4.2-*x* NCs, *x* represents either the reaction temperature or the parameter related to ligands. The exact amount of chemicals with purity less than 99.9% was calculated after considering their respective purity. For oleylamine, the purity of 85% was used for the calculation.

Sample	Cs ₂ CO ₃ (g)	Sn(Oct) ₂ (mL)	TMSI (mL)	TMSBr (mL)	OA (mL)	OAm (mL)	TOP (mL)	Temperature (°C)
0.25:3	0.0326	0.80	0.344	/	0.2	0.2	1.63	180
0.25:3.6	0.0326	0.96	0.344	/	0.2	0.2	1.63	180
0.25:4.2	0.0326	1.12	0.344	/	0.2	0.2	1.63	180
0.25:4.8	0.0326	1.28	0.344	/	0.2	0.2	1.63	180
0.25:5.4	0.0326	1.44	0.344	/	0.2	0.2	1.63	180
0.15:4.2	0.0196	1.12	0.344	/	0.2	0.2	1.63	180
0.35:4.2	0.0456	1.12	0.344	/	0.2	0.2	1.63	180
0.25:4.2:2	0.0326	1.12	0.229	/	0.2	0.2	1.63	180
0.25:4.2:4	0.0326	1.12	0.458	/	0.2	0.2	1.63	180
0.25:4.2-160 °C	0.0326	1.12	0.344	/	0.2	0.2	1.63	160
0.25:4.2-170 °C	0.0326	1.12	0.344	/	0.2	0.2	1.63	170
0.25:4.2-190 °C	0.0326	1.12	0.344	/	0.2	0.2	1.63	190
0.25:4.2-w/o OAm	0.0326	1.12	0.344	/	0.2	/	1.63	180
0.25:4.2-0.1 OAm	0.0326	1.12	0.344	/	0.2	0.1	1.63	180
0.25:4.2-0.3 OAm	0.0326	1.12	0.344	/	0.2	0.3	1.63	180
0.25:4.2-w/o OA	0.0326	1.12	0.344	/	/	0.2	1.63	180
0.25:4.2-0.1 OA	0.0326	1.12	0.344	/	0.1	0.2	1.63	180
0.25:4.2- 0.3 OA	0.0326	1.12	0.344	/	0.3	0.2	1.63	180
CsSnI _{2.5} Br _{0.5}	0.0326	1.12	0.287	0.053	0.2	0.2	1.63	180
CsSnI _{2.25} Br _{0.75}	0.0326	1.12	0.259	0.080	0.2	0.2	1.63	180

Table S2. Summary of the average NC's size and distribution, PL fwhm, PLQY, and average lifetimes (τ_{ave}) for typical samples.

Sample	PLQY (%)	PL FWHM (nm)	Average NC's size (nm)	Size distribution (nm)	τ_{ave} (ns)
0.25:3	4.3	93	26	15-45	0.70
0.25:3.6	8.3	81	29	15-45	0.85
0.25:4.2	13.8	77	33	20-45	1.26
0.25:4.8	18.4	79	37	10-170	1.36
0.25:5.4	8.2	80	63	15-265	0.88

Table S3. Fitting results of PL decay curves, τ_{ave} , PLQYs, radiative (Γ_{rad}) and nonradiative ($\Gamma_{\text{non-rad}}$) decay rates of CsSnI₃ and CsSn(I, Br)₃ NCs. Note that only the decay curve of 0.25:3 was fitted by a tri-exponential function, because it cannot be fitted well by a double-exponential function. It is also necessary to fit the decays of 0.25:3.6, 0.25:4.2 and 0.25:4.8 by a double-exponential function.

Sample	A ₁	τ_1 (ns)	A ₂	τ_2 (ns)	A ₃	τ_3 (ns)	A ₀	Adjusted R- square	τ_{ave} (ns)	PLQY (%)	Γ_{rad} (μs^{-1})	$\Gamma_{\text{non-rad}}$ (μs^{-1})
0.25:3	0.54	0.42	0.50	0.42	0.04	2.13	0.0091	0.9940	0.70	4.3	61.43	1367.14
0.25:3.6	0.93	0.48	0.13	1.63			0.0102	0.9959	0.85	8.3	97.65	1078.82
0.25:4.2	1.00	0.69	0.07	3.07			0.0141	0.9952	1.26	13.8	109.52	684.41
0.25:4.8	0.74	0.61	0.29	1.95			0.0144	0.9977	1.36	18.4	135.29	600.00
0.25:5.4	0.86	0.58	0.17	1.49			0.0163	0.9970	0.88	8.2	93.18	1043.18
CsSnI _{2.5} Br _{0.5}	0.85	0.56	0.09	3.84			0.0835	0.9927	1.94	7.7	39.69	475.77
CsSnI _{2.25} Br _{0.75}	1.03	1.67					0.0251	0.9928	1.67	7.1	42.51	556.29

Table S4. IR vibrational modes and their assignments for CsSnI₃ NCs.

Frequency (cm ⁻¹)	Functional group assigned	References
2926	C-H stretching vibration of methylene group (CH ₂)	2
2854	C-H stretching vibration of methyl group (CH ₃)	2
1745	C=O stretching vibration	2
1649	C=C stretching vibration	3
1541	COO- asymmetric stretching vibration	2,4
1462	C-H bending vibration of methylene group (CH ₂)	5
1377	C-H bending vibration of methyl group (CH ₃)	6
1082	C-P stretching vibration	7,8
721	C-H out-of-plane vibration or C-C stretching vibrations	9-11

Table S5. Summary of ligand density of perovskite NCs solutions.

Sample	Ligand	Ligand density (nm ⁻²)	References
CsPbCl ₃	OA + OAm	25.31	4
CsPbBr ₃ ^a	OA + OAm	6.7	12
CsPbI ₃	OA + OAm	25-40	3
FAPbI ₃	OA + OAm	20-35	3
CsSnI ₃	OA + OAm	1.8	This work
	TOP	2.0	

^a The sample used for the characterization is the product of as-synthesized NCs that undergo one-cycle ligand removal.

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